

## POWER SCHOTTKY RECTIFIER

### MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	<b>30 A</b>
$V_{RRM}$	<b>45 V</b>
$T_j$ (max)	<b>175° C</b>
$V_F$ (max)	<b>0.63 V</b>

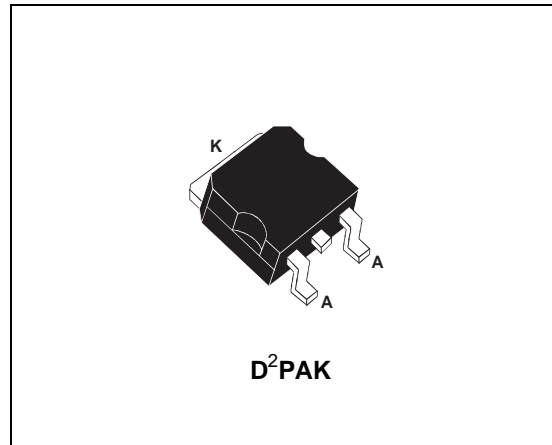
### FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- LOW THERMAL RESISTANCE
- HIGH DISSIPATION MINIATURE PACKAGE

### DESCRIPTION

Single Schottky rectifier suited for switchmode power supply and high frequency DC to DC converters.

Packaged in D<sup>2</sup>PAK surface mount package, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage		45	V
$I_{F(RMS)}$	RMS forward current		50	A
$I_{F(AV)}$	Average forward current	$T_c = 150^\circ\text{C}$ $\delta = 0.5$	30	A
$I_{FSM}$	Surge non repetitive forward current	$t_p = 10\text{ ms}$ Sinusoidal	200	A
$I_{RRM}$	Repetitive peak reverse current	$t_p = 2\ \mu\text{s}$ $F = 1\text{kHz square}$	1	A
$I_{RSM}$	Non Repetitive peak reverse current	$t_p = 100\ \mu\text{s square}$	3	A
$T_{stg}$	Storage temperature range		- 65 to + 175	°C
$T_j$	Maximum operating junction temperature*		175	°C
$dV/dt$	Critical rate of rise of reverse voltage		10000	V/ $\mu\text{s}$

\* :  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  thermal runaway condition for a diode on its own heatsink

# STPS3045G

## THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case	1	$^{\circ}\text{C}/\text{W}$

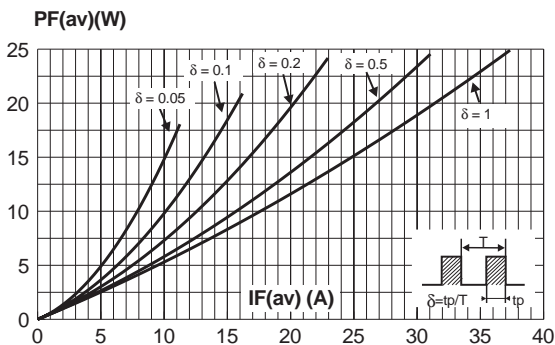
## STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests Conditions		Min.	Typ.	Max.	Unit
$I_R^*$	Reverse leakage current	$T_j = 25^{\circ}\text{C}$	$V_R = V_{RRM}$			500	$\mu\text{A}$
		$T_j = 125^{\circ}\text{C}$			20	80	$\text{mA}$
$V_F^{**}$	Forward voltage drop	$T_j = 125^{\circ}\text{C}$	$I_F = 30\text{ A}$		0.53	0.63	V
		$T_j = 25^{\circ}\text{C}$		$I_F = 60\text{ A}$		0.84	
		$T_j = 125^{\circ}\text{C}$		$I_F = 60\text{ A}$		0.68	

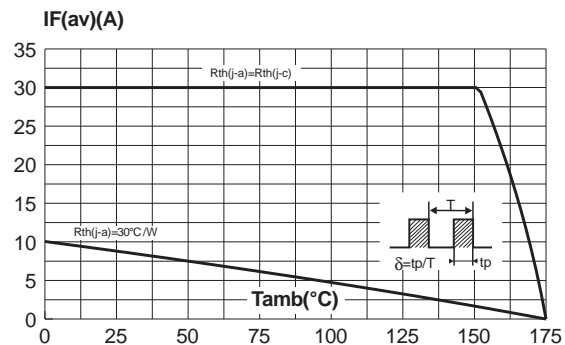
Pulse test : \*  $t_p = 5\text{ ms}$ ,  $\delta < 2\%$   
 \*\*  $t_p = 380\text{ }\mu\text{s}$ ,  $\delta < 2\%$

To evaluate the conduction losses use the following equation :  
 $P = 0.48 \times I_{F(AV)} + 0.005 I_{F(RMS)}^2$

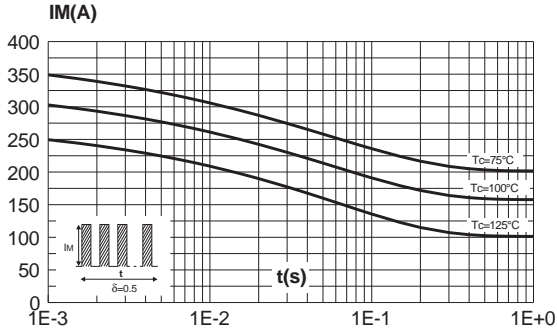
**Fig. 1:** Average forward power dissipation versus average forward current.



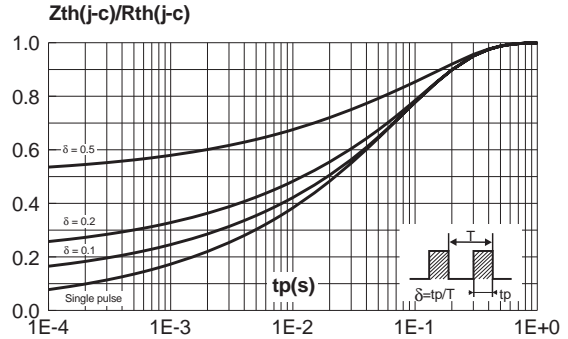
**Fig. 2:** Average forward current versus ambient temperature ( $\delta=0.5$ ).



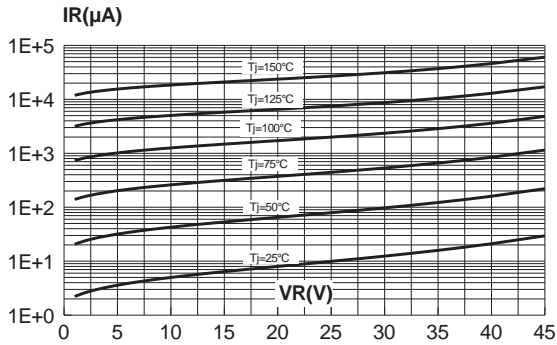
**Fig. 3:** Non repetitive surge peak forward current versus overload duration (maximum values).



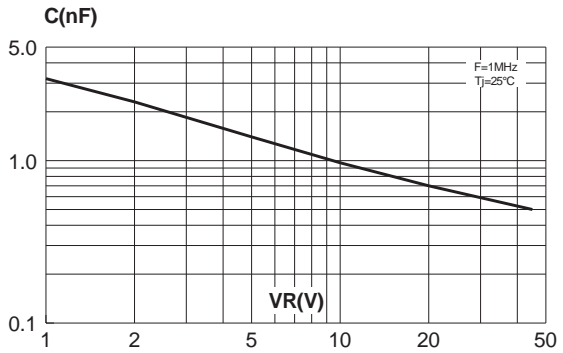
**Fig. 4:** Relative variation of thermal impedance junction to case versus pulse duration.



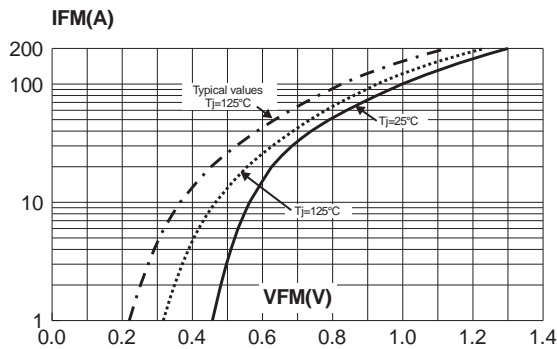
**Fig. 5:** Reverse leakage current versus reverse voltage applied (typical values)



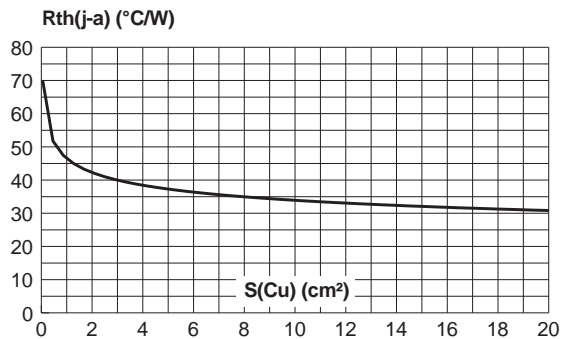
**Fig. 6:** Junction capacitance versus reverse voltage applied (typical values).



**Fig. 7:** Forward voltage drop versus forward current (maximum values).

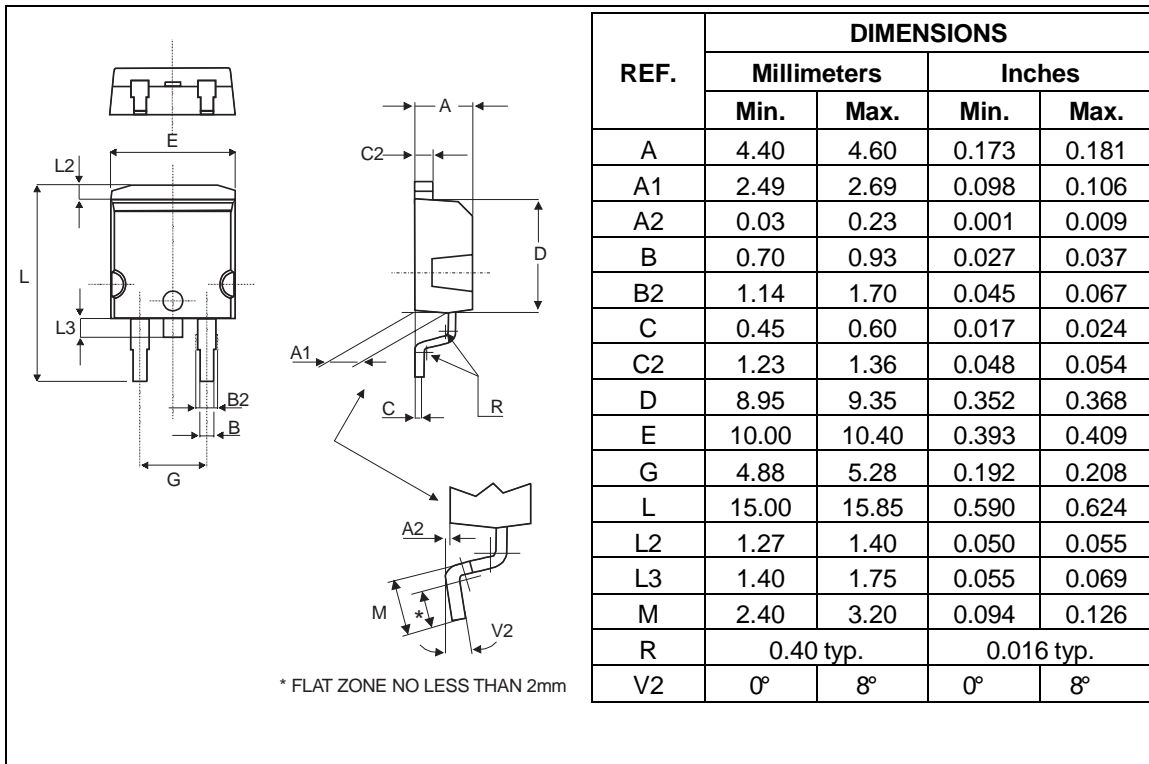


**Fig. 8:** Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board, copper thickness:  $35\mu\text{m}$ )

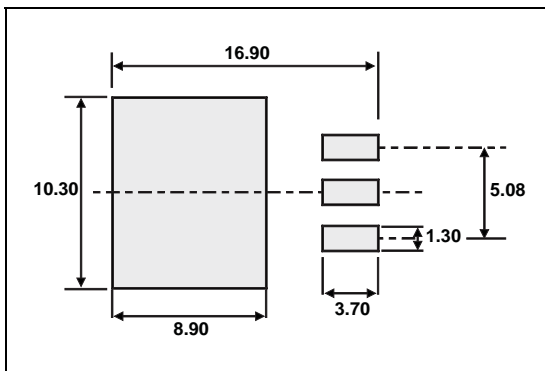


# STPS3045G

## PACKAGE MECHANICAL DATA D<sup>2</sup>PAK



## FOOTPRINT DIMENSIONS (in millimeters)



Type	Marking	Package	Weight	Base qty	Delivery mode
STPS3045G	STPS3045G	D <sup>2</sup> PAK	1.48g	50	Tube
STPS3045G-TR	STPS3045G	D <sup>2</sup> PAK	1.48g	500	Tape & Reel

- Epoxy meets UL94, V0

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